

Vishay General Semiconductor

## **High Current Density Surface Mount Glass-Passivated Rectifiers**

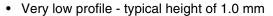




DO-220AA (SMP)

PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	1 A						
$V_{RRM}$	100 V to 1000 V						
I <sub>R</sub>	1 μΑ						
V <sub>F</sub>	0.95 V						
T <sub>J</sub> max.	150 °C						

#### **FEATURES**





· Ideal for automated placement

· Glass passivated chip junction

· Low forward voltage drop

· Low thermal resistance

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

General purpose, polarity protection, and rail-to-rail protection in both consumer and automotive applications.

#### **MECHANICAL DATA**

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	S1PB	S1PD	S1PG	S1PJ	S1PK	S1PM	UNIT
Device marking code		SB	SD	SG	SJ	SK	SM	
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	100	200	400	600	800	1000	V
Average forward current I <sub>F(AV)</sub> 1.0								Α
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30						Α
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150					°C	

### S1PB thru S1PM

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)										
PARAMETER	TEST CONDITIONS		SYMBOL	S1PB	S1PD	S1PG	S1PJ	S1PK	S1PM	UNIT
Maximum instantaneous forward voltage (1)	$I_F = 1.0 A$ $I_F = 1.0 A$	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	V <sub>F</sub>	1.1 0.95						٧
Maximum reverse current (2)	rated V <sub>R</sub>	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	1.0 1.0 50 100					μΑ	
Typical reverse recovery time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A		t <sub>rr</sub>	1.8						μs
Typical junction capacitance time	4.0 V, 1 MH	łz	CJ	6.0					pF	

#### Notes:

- (1) Pulse test: 300 µs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER SYMBOL S1PB S1PD S1PG S1P					S1PJ	S1PK	S1PM	UNIT
	$R_{\theta JA}$	105						
Typical thermal resistance <sup>(1)</sup>	$R_{ hetaJL} \ R_{ hetaJC}$	15 20						°C/W

#### Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas.  $R_{\theta JC}$  is measured at the terminal of cathode band.  $R_{\theta JC}$  is measured at the top centre of the body

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
S1PJ-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel			
S1PJ-E3/85A	0.024	85A	10 000	13" diameter plastic tape and reel			
S1PJHE3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel			
S1PJHE3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel			

#### Note:

(1) Automotive grade AEC Q101 qualified

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

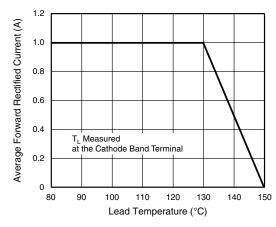


Figure 1. Maximum Forward Current Derating Curve

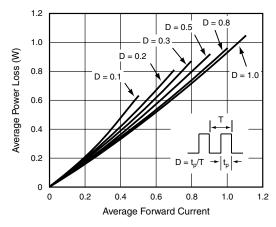


Figure 2. Forward Power Loss Characteristics



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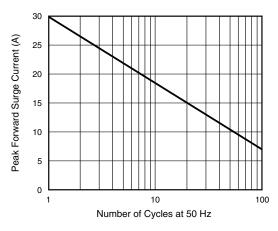


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

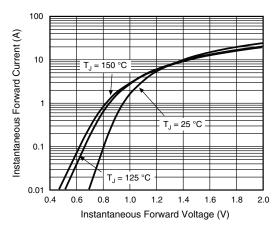


Figure 4. Typical Instantaneous Forward Characteristics

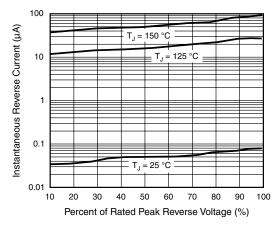


Figure 5. Typical Reverse Leakage Characteristics

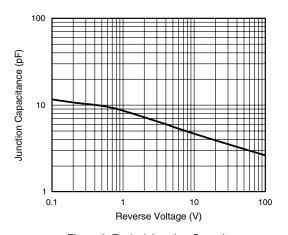


Figure 6. Typical Junction Capacitance

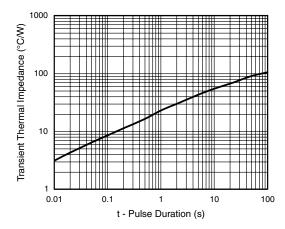


Figure 7. Typical Transient Thermal Impedance

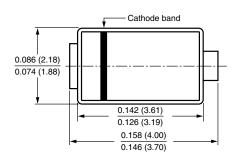
### S1PB thru S1PM

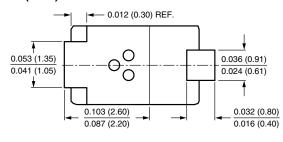
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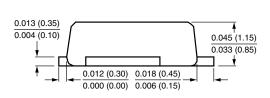


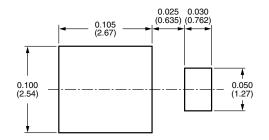
### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### DO-220AA (SMP)











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